

High-speed series

Series/Type:

Date: August 2012

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### **High-speed series**

### **SMD**

#### **Features**

- Very low capacitance values 0.6 up to 10 pF
- ESD protection to IEC 61000-4-2, level 4
- Bidirectional ESD protection in one component
- No change in ESD protection performance at temperatures up to 85 °C (temperature derating)
- Low parasitic inductance
- Low leakage current
- Fast response time <0.5 ns
- Lead-free nickel barrier terminations suitable for lead-free soldering
- RoHS-compatible

### **Applications**

- Interfaces, data lines (USB, IEEE 1394, Ethernet, parallel port, SATA, DisplayPort, etc.), audio lines (digital) and video lines (analog), DVI, HDMI, ICs and I/O ports
- Consumer electronic products (TV, DVD player/recorder, set-top box, game consoles, MP3 player, digital still/video camera, etc.)
- EDP products (desktop and notebook computer, monitor, PDA, printer, memory card, control unit, head set, speaker, HDD, optical drive, etc.)
- Industrial applications
- Mobile phone applications

#### Design

- Multilayer technology
- Nickel barrier termination (Ag/Ni/Sn) for lead-free soldering

#### Marking

 Due to the symmetrical configuration no marking information is needed.

#### General technical data

Maximum DC operating voltage		$V_{DC,max}$	5.6 30	V
Typical capacitance		$C_{typ}$	0.6 10	pF
Air discharge ESD capability	to IEC 61000-4-2	$V_{ESD,air}$	15	kV
Contact discharge ESD capability	to IEC 61000-4-2	V <sub>ESD,contact</sub>	8	kV
Leakage current	$(V_{leak} = 5.6 V)$	I <sub>leak</sub>	1	μΑ
Operating temperature		T <sub>op</sub>	-40/+85	°C
Storage temperature		LCT/UCT	-40/+125	°C

### Single chip



4-fold array



2/4 data + 1 supply





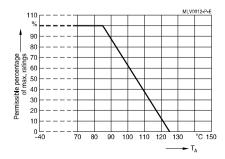
# **High-speed series**

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# Electrical specifications and ordering codes Maximum ratings ( $T_{op,max}$ = 85 °C) and characteristics ( $T_A$ = 25 °C)

Туре	Ordering code	$V_{DC,max}$	V <sub>BR,min</sub>	V <sub>clamp,max</sub>	C <sub>typ</sub>	C <sub>max</sub>			
		v	(1 mA) V	(1 A) V	(1 MHz, 1 V) pF	(1 MHz, 1 V) pF			
Array, 2/4 data + 1 supply, 0506, SOT-666									
CDA3C05GTH B72755D0050H062 5.6 106 395 2.2 3.5									
	1 supply, 1012, SOT-2			000					
CDA6C05GTH	B72735D0050H062	5.6	52	195	7	10			
Array, 4-fold, 0508	3, no semiconductor di	ode equi	valent						
CDA4C16GTH	B72714D0160H060	16	22	66	10	15			
Array, 4-fold, 0612	2, no semiconductor di	ode equi	valent						
CDA5C16GTH	B72724D0160H062	16	80	350	3	5			
Single, 0201, no s	emiconductor diode ed	quivalent							
CDS1C05GTH1	B72440C0050H160	5.5	17	33	7	-			
CDS1C05GTH2	B72440C0050H260	5.5	20	66	3	-			
CDS1C05GTH	B72440D0050H060	5.6	21	70	6	10			
Single, 0402, SOE	)-723								
CDS2C05HDMI1	B72590D0050H160	5.6	150	-	0.6	0.9			
CDS2C05HDMI2	B72590D0050H260	5.6	90	-	0.6	0.9			
CDS2C12GTH	B72590D0120H060	12	20	66	4.5	-			
CDS2C15GTH	B72590D0150H060	15	23	66	10	15			
CDS2C16GTH	B72590D0160H060	16	65	290	2	3			
CDS2C20GTH	B72590D0200H060	20	30	80	10	13			
Single, 0603, SOE	0-523								
CDS3C05HDMI1	B72500D0050H160	5.6	150	-	0.6	0.9			
CDS3C16GTH	B72500D0160H060	16	65	290	3	5			
CDS3C30GTH	B72500D0300H060	30	50	120	10	15			
Single, 1003, SOE	)-323								
CDS4C16GTH	B72570D0160H060	16	38	146	3	5			

# Typical characteristics



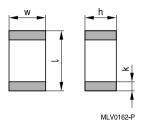


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# **Dimensional drawings**

# Single device

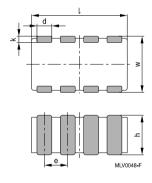


### Dimensions in mm

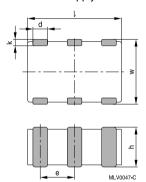
Case (inch)	0201		0402		0603		1003		
size (mm)	0603		1005	1005		1608		2508	
	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Мах.	
I	0.57	0.63	0.85	1.15	1.45	1.75	2.34	2.74	
w	0.27	0.33	0.4	0.6	0.7	0.9	0.7	0.9	
h	0.27	0.33	0.4	0.6	0.7	0.9	0.7	0.9	
k	0.1	0.2	0.1	0.3	0.1	0.4	0.13	0.75	

### Array devices

### 4-fold array



### 2/4 data + 1 supply



### Dimension in mm

Case size	(inch)	0506		0508		0612		1012	
	(mm)	1216		1220		1632		2532	
		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.
1		1.50	1.70	1.8	2.2	3.0	3.4	2.90	3.50
w		1.20	1.40	1.05	1.45	1.45	1.75	2.25	2.75
h		-	0.6	-	0.9	-	0.9	-	1.2
d		0.2	0.4	0.2	0.4	0.25	0.55	0.35	0.65
е		0.4	0.6	0.4	0.6	0.61	0.91	0.8	1.1
k		-	0.35	-	0.35	-	0.35	-	0.45

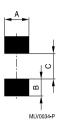


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# Recommended solder pads

# Single device

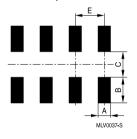


### Dimensions in mm

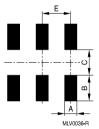
Case size	(inch)	0201	0402	0603	1003
	(mm)	0603	1005	1608	2508
A		0.3	0.6	1.0	0.8
В		0.25	0.6	1.0	0.8
С		0.3	0.5	1.0	1.45

# Array devices

4-fold array



2/4 data + 1 supply



### Dimensions in mm

Case size	(inch) (mm)	0506 1216	0508 1220	0612 1632	1012 2532
	(111111)	1210	1220	1032	2532
A		0.36	0.35	0.5	0.7
В		0.84	0.9	0.7	1.0
С		0.62	0.4	1.2	1.4
E		0.50	0.5	0.76	0.95



# **High-speed series**

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# Pin configurations

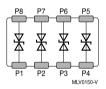
# Single device



Pin	Description
P1	GND
P2	I/O line

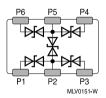
# Array devices

### 4-fold array



Pin	Description
P1	GND
P2	GND
P3	GND
P4	GND
P5	I/O line 1
P6	I/O line 2
P7	I/O line 3
P8	I/O line 4

# 2/4 data + 1 supply



Description
I/O line 1
GND
I/O line 2
I/O line 3
V <sub>DC</sub>
I/O line 4

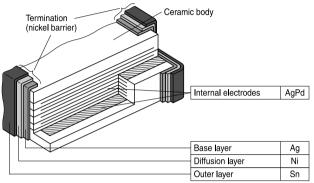


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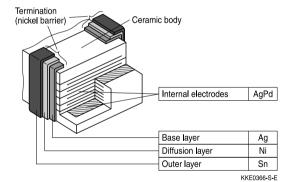
### Termination

# Single device



KKE0484-W-E

# Array device





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# **Delivery mode**

EIA case size	Taping	Reel size	Packing unit	Туре	Ordering code
	1 0	mm	pcs.	. , , , ,	or doming dodd
0201	Cardboard	180	15000	CDS1C05GTH	B72440D0050H060
0201	Cardboard	180	15000	CDS1C05GTH1	B72440C0050H160
0201	Cardboard	180	15000	CDS1C05GTH2	B72440C0050H260
0402	Cardboard	180	10000	CDS2C05HDMI1	B72590D0050H160
0402	Cardboard	180	10000	CDS2C05HDMI2	B72590D0050H260
0402	Cardboard	180	10000	CDS2C12GTH	B72590D0120H060
0402	Cardboard	180	10000	CDS2C15GTH	B72590D0150H060
0402	Cardboard	180	10000	CDS2C16GTH	B72590D0160H060
0402	Cardboard	180	10000	CDS2C20GTH	B72590D0200H060
0506	Blister	180	3000	CDA3C05GTH	B72755D0050H062
0508	Cardboard	180	4000	CDA4C16GTH	B72714D0160H060
0603	Cardboard	180	4000	CDS3C05HDMI1	B72500D0050H160
0603	Cardboard	180	4000	CDS3C16GTH	B72500D0160H060
0603	Cardboard	180	4000	CDS3C30GTH	B72500D0300H060
0612	Blister	180	3000	CDA5C16GTH	B72724D0160H062
1003	Cardboard	180	4000	CDS4C16GTH	B72570D0160H060
1012	Blister	180	2000	CDA6C05GTH	B72735D0050H062

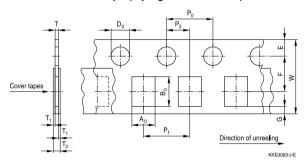


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# 1 Taping and packing for chip and array CeraDiodes

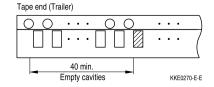
# 1.1 Cardboard tape (taping to IEC 60286-3)

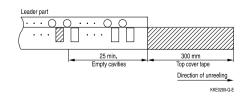


### Dimensions in mm

Case size (inch)		0201	0402	0603	1003	0508	Tolerance
(mm)		0603	1005	1608	2508	1220	
Compartment width	A <sub>0</sub>	0.38 ±0.05	0.6	0.95	1.0	1.6	±0.2
Compartment length	B <sub>0</sub>	0.68 ±0.05	1.15	1.8	2.85	2.4	±0.2
Sprocket hole diameter	$D_0$	1.5 ±0.1	1.5	1.5	1.5	1.5	+0.1/ -0
Sprocket hole pitch	$P_0$	4.0 ±0.1 <sup>1)</sup>	4.0	4.0	4.0	4.0	±0.11)
Distance center hole to center	P <sub>2</sub>	2.0 ±0.05	2.0	2.0	2.0	2.0	±0.05
compartment							
Pitch of component compartments	$P_1$	2.0 ±0.05	2.0	4.0	4.0	4.0	±0.1
Tape width	W	8.0 ±0.3	8.0	8.0	8.0	8.0	±0.3
Distance edge to center of hole	Е	1.75 ±0.1	1.75	1.75	1.75	1.75	±0.1
Distance center hole to center compartment	F	3.5 ±0.05	3.5	3.5	3.5	3.5	±0.05
Distance compartment to edge	G	1.35 min.	0.75	0.75	0.75	0.75	min.
Thickness tape	Т	0.35 ±0.02	0.6	0.9	1.0	0.95	max.
Overall thickness	T <sub>2</sub>	0.4 min.	0.7	1.1	1.1	1.12	max.

 $<sup>^{1)} \</sup>le \pm 0.2$  mm over 10 sprocket holes



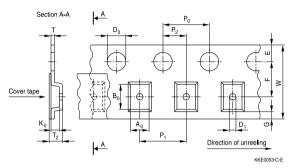




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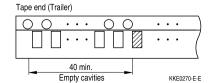
# 1.2 Blister tape (taping to IEC 60286-3)

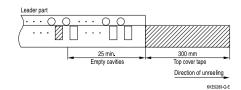


### Dimensions in mm

Case size (inch)		0506	0612	1012	Tolerance
(mm)		1216	1632	2532	
Compartment width	$A_0$	1.5	1.9	2.8	±0.2
Compartment length	B <sub>0</sub>	1.8	3.5	3.5	±0.2
Compartment height	K <sub>0</sub>	0.8	1.8	1.8	max.
Sprocket hole diameter	D <sub>0</sub>	1.5	1.5	1.5	+0.1/ -0
Compartment hole diameter	D <sub>1</sub>	1.0	1.0	1.0	min.
Sprocket hole pitch	P <sub>0</sub>	4.0	4.0	4.0	±0.11)
Distance center hole to center compartment	P <sub>2</sub>	2.0	2.0	2.0	±0.05
Pitch of component compartments	P <sub>1</sub>	4.0	4.0	4.0	±0.1
Tape width	W	8.0	8.0	8.0	±0.3
Distance edge to center of hole	Е	1.75	1.75	1.75	±0.1
Distance center hole to center compartment	F	3.5	3.5	3.5	±0.05
Distance compartment to edge	G	0.75	0.75	0.75	min.
Thickness tape	Т	0.3	0.3	0.3	max.
Overall thickness	T <sub>2</sub>	1.3	2.5	2.5	max.

 $<sup>^{1)} \</sup>le \pm 0.2$  mm over 10 sprocket holes



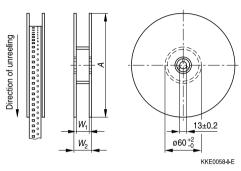




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# 1.3 Reel packing



### Dimensions in mm

		Dimensions	Tolerance	Dimensions	Tolerance
Reel diameter	Α	180	+0/ -3	330	±2
Reel width (inside)	W <sub>1</sub>	8.4	+1.5/ -0	8.4	+1.5/ -0
Reel width (outside)	$W_2$	14.4	max.	14.4	max.

Package: 8-mm tape Reel material: Plastic

# 1.4 Packing units

Case size	Ø 180-mm reel	Ø 330-mm reel	Таре
(inch) / (mm)	pieces	pieces	
0201 / 0603	15000	-	cardboard
0402 / 1005	10000	50000	cardboard
0603 / 1608	4000	16000	cardboard
1003 / 2508	4000	16000	cardboard
0506 / 1216	3000	12000	blister
0508 / 1220	4000	16000	cardboard
0612 / 1632	3000	12000	blister
1012 / 2532	2000	8000	blister



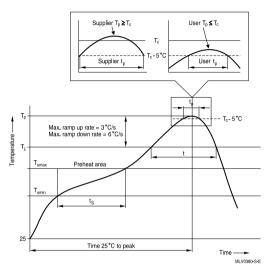
### **High-speed series**

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### Soldering directions

### 1 Reflow soldering temperature profile

Recommended temperature characteristic for reflow soldering following JEDEC J-STD-020D



Profile feature		Sn-Pb eutectic assembly	Pb-free assembly	
Preheat and soak				
- Temperature min	T <sub>smin</sub>	100 °C	150 °C	
- Temperature max	T <sub>smax</sub>	150 °C	200 °C	
- Time	$t_{smin}$ to $t_{smax}$	60 120 s	60 180 s	
Average ramp-up rate	$T_{smax}$ to $T_p$	3 °C/ s max.	3 °C/ s max.	
Liquidous temperature	T <sub>L</sub>	183 °C	217 °C	
Time at liquidous	t_	60 150 s	60 150 s	
Peak package body temperature	T <sub>p</sub> <sup>1)</sup>	220 °C 235 °C <sup>2)</sup>	245 °C 260 °C <sup>2)</sup>	
Time (t <sub>P</sub> ) <sup>3)</sup> within 5 °C of specified		20 s <sup>3)</sup>	30 s <sup>3)</sup>	
classification temperature (T <sub>c</sub> )		20 5%	30 8-7	
Average ramp-down rate	T <sub>p</sub> to T <sub>smax</sub>	6 °C/ s max.	6 °C/ s max.	
Time 25 °C to peak temperature		maximum 6 min	maximum 8 min	

<sup>1)</sup> Tolerance for peak profile temperature (T<sub>P</sub>) is defined as a supplier minimum and a user maximum.

**Note:** All temperatures refer to topside of the package, measured on the package body surface. Number of reflow cycles: 3

<sup>2)</sup> Depending on package thickness. For details please refer to JEDEC J-STD-020D.

<sup>3)</sup> Tolerance for time at peak profile temperature (t<sub>P</sub>) is defined as a supplier minimum and a user maximum.



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### 2 Soldering guidelines

The use of mild, non-activated fluxes for soldering is recommended, as well as proper cleaning of the PCB

The components are suitable for reflow soldering to JEDEC J-STD-020D.

### 3 Solder joint profiles / solder quantity

#### 3.1 Cement quantity

The component is fixed onto the circuit board with cement prior to soldering. It must still be able to move slightly. When the board is placed into the reflow oven, excessively rigid fixing can lead to high forces acting on the component and thus to a break. In addition, too much cement can lead to unsymmetrical stressing and thus to mechanical fracture of the component. The cement must also be so soft during mounting that no mechanical stressing occurs.

#### 3.2 Mounting the components on the board

It is best to mount the components on the board before soldering so that one termination does not enter the oven first and the second termination is soldered subsequently. The ideal case is simultaneous wetting of both terminations.

#### 3.3 Solder joint profiles

If the meniscus height is too low, that means the solder quantity is too low, the solder joint may break, i.e. the component becomes detached from the joint. This problem is sometimes interpreted as leaching of the external terminations.

If the solder meniscus is too high, i.e. the solder quantity is too large, the vise effect may occur. As the solder cools down, the solder contracts in the direction of the component. If there is too much solder on the component, it has no leeway to evade the stress and may break, as in a vise.

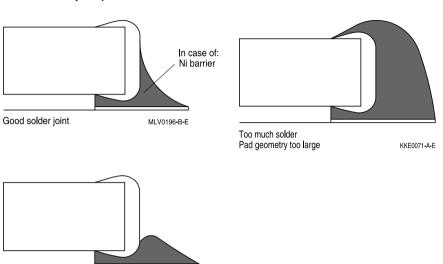


Poor wetting

### **High-speed series**

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# 3.3.1 Solder joint profiles for nickel barrier termination



Good and poor solder joints caused by amount of solder in infrared reflow soldering

KKE0072-I-E



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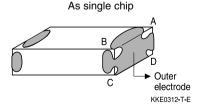
### 4 Solderability tests

	I	T	I	T
Test	Standard	Test conditions /	Test conditions /	Criteria / test results
		Sn-Pb soldering	Pb-free soldering	
Wettability	IEC	Immersion in	Immersion in	Covering of 95%
	60068-2-58	60/40 SnPb solder	Sn96.5Ag3.0Cu0.5	of end termination,
		using non-activated	solder using non- or	checked by visual
		flux at 215 ±3 °C for	low activated flux	inspection
		3 ±0.3 s	at 245 ±5 °C	
			for 3 ±0.3 s	
Leaching	IEC	Immersion in	Immersion in	No leaching of
resistance	60068-2-58	60/40 SnPb	Sn96.5Ag3.0Cu0.5	contacts
		solder using	solder using non- or	
		mildly activated flux	low activated flux	
		without preheating	without preheating	
		at 255 ±5 °C	at 255 ±5 °C	
		for 10 ±1 s	for 10 ±1 s	
Tests of	IEC	Immersion in	Immersion in	Capacitance change:
resistance to	60068-2-58	60/40 SnPb for 10 s	Sn96.5Ag3.0Cu0.5	−15% ≤ΔC ≤15%
soldering heat		at 260 °C	for 10 s at 260 °C	
for SMDs				

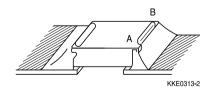
#### Note:

### Leaching of the termination

Effective area at the termination might be lost if the soldering temperature and/or immersion time are not kept within the recommended conditions. Leaching of the outer electrode should not exceed 25% of the chip end area (full length of the edge A-B-C-D) and 25% of the length A-B, shown below as mounted on the substrate.



As mounted on substrate





### **High-speed series**

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### 5 Notes for proper soldering

#### 5.1 Preheating and cooling

- The average ramp-up rate must not exceed 3 °C/s.
- The cooling rate must not exceed 8 °C/s.

### 5.2 Repair / rework

Manual soldering with a soldering iron must be avoided, hot-air methods are recommended for making repairs.

#### 5.3 Cleaning

All environmentally compatible agents are suitable for cleaning. Select the appropriate cleaning solution according to the type of flux used. The temperature difference between the components and cleaning liquid must not be greater than 100 °C. Ultrasonic cleaning should be carried out with the utmost caution. Too high ultrasonic power can impair the adhesive strength of the metallized surfaces. Insufficient or excessive cleaning can be detrimental to CeraDiode performance.

### 5.4 Solder paste printing (reflow soldering)

An excessive application of solder paste results in too high a solder fillet, thus making the chip more susceptible to mechanical and thermal stress. This will lead to the formation of cracks. Too little solder paste reduces the adhesive strength on the outer electrodes and thus weakens the bonding to the PCB. The solder should be applied smoothly to the end surface to a height of min. 0.2 mm.

#### 5.5 Selection of flux

Used flux should have less than or equal to 0.1 wt % of halogenated content, since flux residue after soldering could lead to corrosion of the termination and/or increased leakage current on the surface of the CeraDiode. Strong acidic flux must not be used. The amount of flux applied should be carefully controlled, since an excess may generate flux gas, which in turn is detrimental to solderability.

#### 5.6 Storage

Solderability is guaranteed for one year from date of delivery, provided that components are stored in their original packages.

Storage temperature: -25 °C to +45 °C

Relative humidity: ≤75% annual average, ≤95% on 30 days a year

The solderability of the external electrodes may deteriorate if SMDs are stored where they are exposed to high humidity, dust or harmful gas (hydrogen chloride, sulfurous acid gas or hydrogen sulfide).

Do not store SMDs where they are exposed to heat or direct sunlight. Otherwise the packing material may be deformed or SMDs may stick together, causing problems during mounting.

After opening the factory seals, such as polyvinyl-sealed packages, it is recommended to use the SMDs as soon as possible.



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### **SMD**

### 5.7 Placement of components on circuit board

It is of advantage to place the components on the board before soldering so that their two terminals do not enter the solder oven at different times. Ideally, both terminals should be wetted simultaneously.

### 5.8 Soldering caution

- Sudden heating or cooling of the component results in thermal destruction by cracks.
- An excessively long soldering time or high soldering temperature results in leaching of the outer electrodes, causing poor adhesion due to loss of contact between electrodes and termination.
- Avoid manual soldering with a soldering iron.
- Wave soldering must not be applied for CeraDiodes designated for reflow soldering only.
- Keep to the recommended down-cooling rate.

#### 5.9 Standards

CECC 00802 IEC 60068-2-58 IEC 60068-2-20 JEDEC J-STD-020D



# **High-speed series**

# **SMD**

### Symbols and terms

CeraDiode	Semiconductor diode	
C <sub>max</sub>		Maximum capacitance
$C_{typ}$		Typical capacitance
I <sub>BR</sub>	$I_R$ , $I_T$	(Reverse) current @ breakdown voltage
l <sub>leak</sub>	I <sub>RM</sub>	(Reverse) leakage current
I <sub>PP</sub>	I <sub>PP</sub>	Current @ clamping voltage
$I_{PP}$	$I_P$ , $I_{PP}$	Peak pulse current
P <sub>PP</sub>	P <sub>PP</sub>	Peak pulse power
T <sub>op</sub>		Operating temperature
$T_{stg}$		Storage temperature
$V_{BR}$	$V_{BR}$	(Reverse) breakdown voltage
$V_{BR,min}$		Minimum breakdown voltage
$V_{clamp}$	$V_{cl}$ , $V_{C}$	Clamping voltage
$V_{\text{clamp,max}}$		Maximum clamping voltage
$V_{DC}$	$V_{\text{RM}}, V_{\text{RWM}}, V_{\text{WM}}, V_{\text{DC}}$	(Reverse) stand-off voltage, working voltage, operating voltage
$V_{DC,max}$		Maximum DC operating voltage
V <sub>ESD,air</sub>		Air discharge ESD capability
V <sub>ESD,contact</sub>		Contact discharge ESD capability
V <sub>leak</sub>	$V_{RM}, V_{RWM}, V_{WM}, V_{DC}$	(Reverse) voltage @ leakage current
- *)	I <sub>F</sub>	Current @ forward voltage
- *)	I <sub>RM</sub> , I <sub>RM,max</sub> @V <sub>RM</sub>	(Reverse) current @ maximum reverse
,		stand-off voltage, working voltage, operating voltage
- *)	V <sub>F</sub>	Forward voltage

<sup>\*)</sup> Not applicable due to bidirectional characteristics of CeraDiodes



### **High-speed series**

**SMD** 

### Cautions and warnings

#### General

Some parts of this publication contain statements about the suitability of our CeraDiodes for certain areas of application, including recommendations about incorporation/design-in of these products into customer applications. The statements are based on our knowledge of typical requirements often made of our CeraDiodes in the particular areas. We nevertheless expressly point out that such statements cannot be regarded as binding statements about the suitability of our CeraDiodes for a particular customer application. As a rule, EPCOS is either unfamiliar with individual customer applications or less familiar with them than the customers themselves. For these reasons, it is always incumbent on the customer to check and decide whether the CeraDiodes with the properties described in the product specification are suitable for use in a particular customer application.

- Do not use EPCOS CeraDiodes for purposes not identified in our specifications, application notes and data books.
- Ensure the suitability of a CeraDiode in particular by testing it for reliability during design-in. Always evaluate a CeraDiode under worst-case conditions.
- Pay special attention to the reliability of CeraDiodes intended for use in safety-critical applications (e.g. medical equipment, automotive, spacecraft, nuclear power plant).

#### **Design notes**

- Always connect a CeraDiode in parallel with the electronic circuit to be protected.
- Consider maximum rated power dissipation if a CeraDiode has insufficient time to cool down between a number of pulses occurring within a specified isolated time period. Ensure that electrical characteristics do not degrade.
- Consider derating at higher operating temperatures. Choose the highest voltage class compatible with derating at higher temperatures.
- Surge currents beyond specified values will puncture a CeraDiode. In extreme cases a CeraDiode will burst.
- If steep surge current edges are to be expected, make sure your design is as low-inductance as possible.
- In some cases the malfunctioning of passive electronic components or failure before the end of their service life cannot be completely ruled out in the current state of the art, even if they are operated as specified. Do not use CeraDiodes in applications requiring a very high level of operational safety and especially when the malfunction or failure of a passive electronic component could endanger human life or health (e.g. in accident prevention, life-saving systems, or automotive battery line applications such as clamp 30), ensure by suitable design of the application or other measures (e.g. installation of protective circuitry or redundancy) that no injury or damage is sustained by third parties in the event of such a malfunction or failure.
- Specified values only apply to CeraDiodes that have not been subject to prior electrical, mechanical or thermal damage. The use of CeraDiodes in line-to-ground applications is therefore not advisable, and it is only allowed together with safety countermeasures like thermal fuses.



### **High-speed series**

### **SMD**

### Storage

- Only store CeraDiodes in their original packaging. Do not open the package before storage.
- Storage conditions in original packaging: temperature -25 to +45°C, relative humidity ≤75% annual average, maximum 95%, dew precipitation is inadmissible.
- Do not store CeraDiodes where they are exposed to heat or direct sunlight. Otherwise the packaging material may be deformed or CeraDiodes may stick together, causing problems during mounting.
- Avoid contamination of the CeraDiode surface during storage, handling and processing.
- Avoid storing CeraDiodes in harmful environments where they are exposed to corrosive gases for example (SO<sub>x</sub>, CI).
- Use CeraDiodes as soon as possible after opening factory seals such as polyvinyl-sealed packages.
- Solder CeraDiodes after shipment from EPCOS within the time specified: 12 months.

### Handling

- Do not drop CeraDiodes and allow them to be chipped.
- Do not touch CeraDiodes with your bare hands gloves are recommended.
- Avoid contamination of the CeraDiode surface during handling.
- Washing processes may damage the product due to the possible static or cyclic mechanical loads (e.g. ultrasonic cleaning). They may cause cracks to develop on the product and its parts, which might lead to reduced reliability or lifetime.

#### Mounting

- When CeraDiodes are encapsulated with sealing material or overmolded with plastic material, be aware that potting, sealing or adhesive compounds can produce chemical reactions in the CeraDiode ceramic that will degrade its electrical characteristics and reduce its lifetime.
- Make sure an electrode is not scratched before, during or after the mounting process.
- Make sure contacts and housings used for assembly with CeraDiodes are clean before mounting.
- The surface temperature of an operating CeraDiode can be higher. Ensure that adjacent components are placed at a sufficient distance from a CeraDiode to allow proper cooling.
- Avoid contamination of the CeraDiode surface during processing.
- Only CeraDiodes with an Ni barrier termination are approved for lead-free soldering.

### Soldering

- Complete removal of flux is recommended to avoid surface contamination that can result in an instable and/or high leakage current.
- Use resin-type or non-activated flux.
- Bear in mind that insufficient preheating may cause ceramic cracks.
- Rapid cooling by dipping in solvent is not recommended, otherwise a component may crack.



### **High-speed series**

### **SMD**

### Operation

- Use CeraDiodes only within the specified operating temperature range.
- Use CeraDiodes only within specified voltage and current ranges.
- Environmental conditions must not harm a CeraDiode. Only use them in normal atmospheric conditions. Reducing the atmosphere (e.g. hydrogen or nitrogen atmosphere) is prohibited.
- Prevent a CeraDiode from contacting liquids and solvents. Make sure that no water enters a CeraDiode (e.g. through plug terminals).
- Avoid dewing and condensation.
- EPCOS CeraDiodes are designed for encased applications. Under all circumstances avoid exposure to:
  - direct sunlight
  - rain or condensation
  - steam, saline spray
  - corrosive gases
  - atmosphere with reduced oxygen content
- EPCOS CeraDiodes are not suitable for switching applications or voltage stabilization where static power dissipation is required.
- CeraDiodes are designed for ESD protection only.

This listing does not claim to be complete, it merely reflects the experience of EPCOS AG.



### Important notes

The following applies to all products named in this publication:

- 1. Some parts of this publication contain statements about the suitability of our products for certain areas of application. These statements are based on our knowledge of typical requirements that are often placed on our products in the areas of application concerned. We nevertheless expressly point out that such statements cannot be regarded as binding statements about the suitability of our products for a particular customer application. As a rule, EPCOS is either unfamiliar with individual customer applications or less familiar with them than the customers themselves. For these reasons, it is always ultimately incumbent on the customer to check and decide whether an EPCOS product with the properties described in the product specification is suitable for use in a particular customer application.
- 2. We also point out that in individual cases, a malfunction of electronic components or failure before the end of their usual service life cannot be completely ruled out in the current state of the art, even if they are operated as specified. In customer applications requiring a very high level of operational safety and especially in customer applications in which the malfunction or failure of an electronic component could endanger human life or health (e.g. in accident prevention or lifesaving systems), it must therefore be ensured by means of suitable design of the customer application or other action taken by the customer (e.g. installation of protective circuitry or redundancy) that no injury or damage is sustained by third parties in the event of malfunction or failure of an electronic component.
- 3. The warnings, cautions and product-specific notes must be observed.
- 4. In order to satisfy certain technical requirements, some of the products described in this publication may contain substances subject to restrictions in certain jurisdictions (e.g. because they are classed as hazardous). Useful information on this will be found in our Material Data Sheets on the Internet (www.epcos.com/material). Should you have any more detailed questions, please contact our sales offices.
- 5. We constantly strive to improve our products. Consequently, the products described in this publication may change from time to time. The same is true of the corresponding product specifications. Please check therefore to what extent product descriptions and specifications contained in this publication are still applicable before or when you place an order. We also reserve the right to discontinue production and delivery of products. Consequently, we cannot guarantee that all products named in this publication will always be available. The aforementioned does not apply in the case of individual agreements deviating from the foregoing for customer-specific products.
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- 7. The trade names EPCOS, BAOKE, Alu-X, CeraDiode, CeraLink, CSMP, CSSP, CTVS, DeltaCap, DigiSiMic, DSSP, FilterCap, FormFit, MiniBlue, MiniCell, MKD, MKK, MLSC, MotorCap, PCC, PhaseCap, PhaseCube, PhaseMod, PhiCap, SIFERRIT, SIFI, SIKOREL, SilverCap, SIMDAD, SiMic, SIMID, SineFormer, SIOV, SIP5D, SIP5K, ThermoFuse, WindCap are trademarks registered or pending in Europe and in other countries. Further information will be found on the Internet at www.epcos.com/trademarks.

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Общество с ограниченной ответственностью «МосЧип» ИНН 7719860671 / КПП 771901001 Адрес: 105318, г.Москва, ул.Щербаковская д.3, офис 1107

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# Офис по работе с юридическими лицами:

105318, г. Москва, ул. Щербаковская д. 3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru moschip.ru\_6 moschip.ru\_4 moschip.ru\_9